

Notice of References Cited	Application/Control No. 09/660,317		Applicant(s)/Patent Under Reexamination CAMRAS ET AL.	
	Examiner Monica Lewis		Art Unit 2822	Page 1 of 1

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.